

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Bradley R. Johnson et al.

Application No. 10/646,264**Filed:** August 22, 2003**Confirmation No.** 9466**For:** CHALCOGENIDE GLASS
NANOSTRUCTURES**Examiner:** David P. Turocy**Art Unit:** 1762**Attorney Reference No.** 23-70761-01**CERTIFICATE OF MAILING**

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PURSUANT TO 37 C.F.R. § 1.97(b)(4)

Listed on the accompanying form PTO-1449 and enclosed herewith are several English-language documents. Applicants respectfully request that these documents be listed as references cited on the issued patent.

Copies of United States patents and United States published patent applications do not have to be provided to the Patent Office (37 C.F.R. 1.98(a)(2)(ii)). Copies of unpublished U.S. applications do not have to be provided, as long as the application is available on PAIR, as this requirement of 37 C.F.R. § 1.98(a)(2)(iii) has been waived by the United States Patent and Trademark Office pursuant to the Official Gazette Notice on October 19, 2004 (1287 OG 163). Applicants will provide copies of such patents or applications upon request.

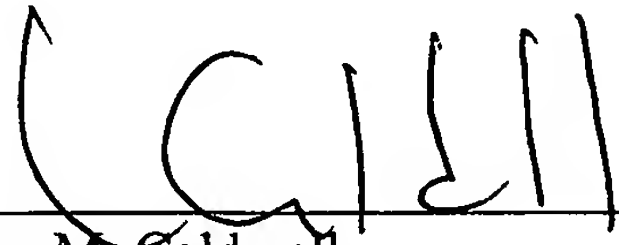
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The filing of this IDS shall not be construed to be an admission that the information cited in the statement is, or is considered to be, prior art or otherwise material to patentability as defined in 37 C.F.R. §1.56.

Respectfully submitted,

KLARQUIST SPARKMAN, LLP

By



Lisa M. Caldwell
Registration No: 41,653

One World Trade Center, Suite 1600
121 S.W. Salmon Street
Portland, Oregon 97204
Telephone: (503) 595-5300
Facsimile: (503) 595-5301

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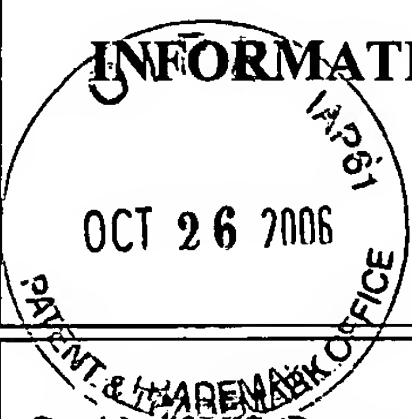
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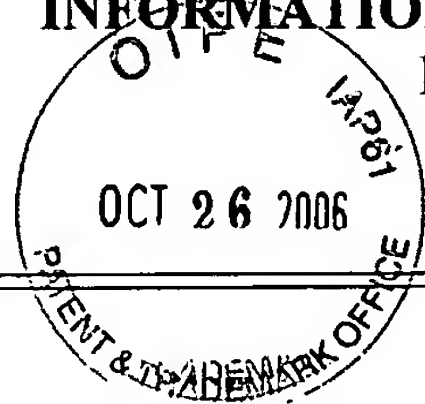
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FOREIGN PATENT DOCUMENTS

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		Zhang et al., "Morphology and growth mechanism study of self-assembled silicon nanowires synthesized by thermal evaporation," <i>Chemical Physics Letters</i> , Vol. 337, pp. 18-24 (2001).	

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